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SGA-4586(Z)

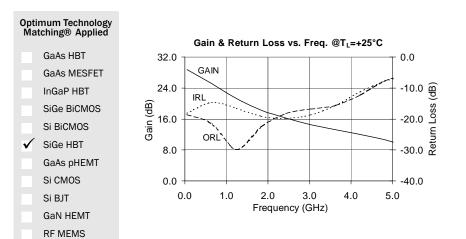
DC to 4000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER



RFMD Green, RoHS Compliant, Pb-Free (Z Part Number) Package: SOT-86

Product Description

The SGA-4586 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- High Gain: 17.9dB at 1950MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition		
Farameter	Min.	Тур.	Max.	Unit	Condition		
Small Signal Gain	22.0	24.0	26.5	dB	850MHz		
		17.9		dB	1950MHz		
		16.3		dB	2400MHz		
Output Power at 1dB Compression		16.5		dBm	850MHz		
		13.7		dBm	1950MHz		
Output Third Intercept Point		28.6		dBm	850MHz		
		27.7		dBm	1950MHz		
Bandwidth Determined by Return Loss (>10dB)		4000		MHz	>10dB		
Input Return Loss		19.4		dB	1950MHz		
Output Return Loss		21.5		dB	1950MHz		
Noise Figure		1.9		dB	1950MHz		
Device Operating Voltage		3.6		V			
Device Operating Current	41	45	49	mA			
Thermal Resistance (Junction - Lead)		97		°C/W			

 $\label{eq:conditions: V_S=8V, I_D=45 mA Typ., OIP_3 Tone Spacing=1 MHz, P_{OUT} per tone=-5 dBm, R_{BIAS}=100 \Omega, T_L=25 \,^\circ\text{C}, Z_S=Z_L=50 \Omega, T_L=25 \,^\circ\text{C}, T_L=25 \,^\circ\text{C$

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Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I _D)	90	mA
Max Device Voltage (V _D)	5	V
Max RF Input Power	+18	dBm
Max Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Typical Performance at Key Operating Frequencies

Caution! ESD sensitive device.

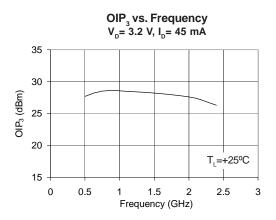
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

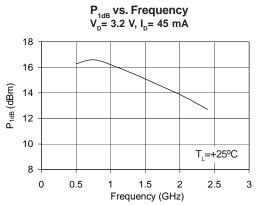
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

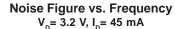
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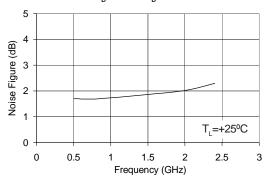
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB		26.2	24.0	18.0	16.3	
Output Third Order Intercept Point	dBm		27.7	28.6	26.0	26.3	
Output Power at 1dB Compression	dBm		16.3	16.5	14.0	12.7	
Input Return Loss	dB	18.1	14.9	15.0	19.4	19.8	16.1
Output Return Loss	dB	18.5	20.6	24.4	21.5	18.3	16.1
Reverse Isolation	dB	30.1	28.4	26.6	21.2	19.3	15.8
Noise Figure	dB		1.7	1.7	1.9	2.3	

Test Conditions: $V_S = 8V$, $I_D = 45$ mA Typ., OIP₃ Tone Spacing = 1MHz, P_{OUT} per tone = -5 dBm, $R_{BIAS} = 100\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



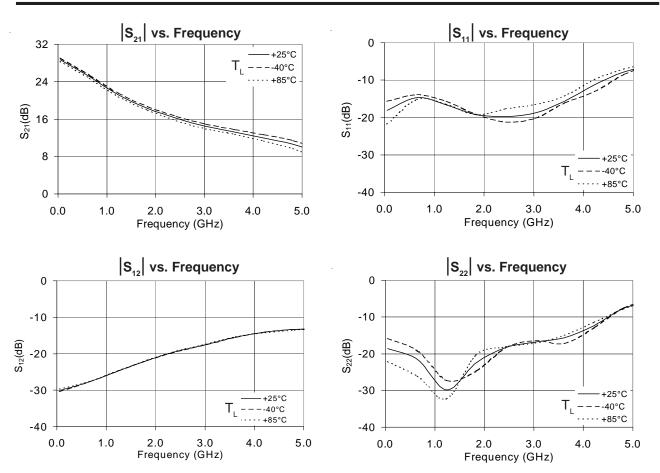












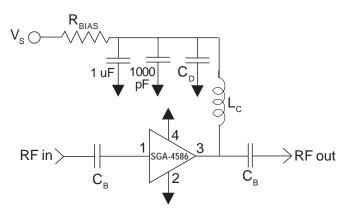
Typical RF Performance Over Temperature (Bias: V_p = 3.2 V, I_p = 45 mA (Typ.))

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Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper opera- tion.

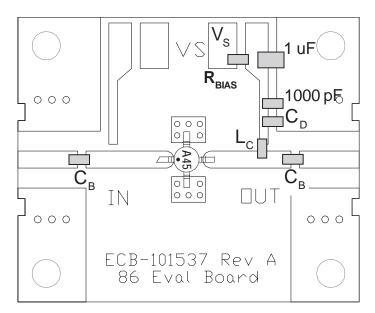




Reference	Frequency (Mhz)							
Designator	500	850	1950	2400	3500			
C _B	220 pF	100 pF	68 pF	56 pF	39 pF			
C _D	100 pF	68 pF	22 pF	22 pF	15 pF			
L _c	68 nH	33 nH	22 nH	18 nH	15 nH			

Recommended Bias Resistor Values for I_p =45mA R _{BIAS} =(V _s -V _p) / I _p					
Supply Voltage(V _s)	6 V	8 V	10 V	12 V	
R _{BIAS} 51 Ω 100 Ω 150 Ω 180 Ω					
Note: $\mathrm{R}_{_{\mathrm{BIAS}}}$ provides DC bias stability over temperature.					

Evaluation Board Layout

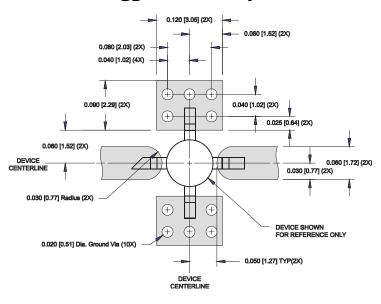


Mounting Instructions

- Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- 2. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.



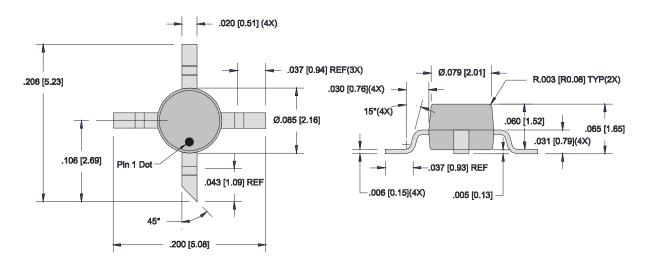




Suggested Pad Layout

Package Drawing

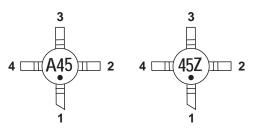
Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.







Part Identification



Ordering Information

Part Number	Reel Size	Devices/Reel
SGA-4586	13"	3000
SGA-4586Z	13"	3000